## **Features**

- Low-voltage and Standard-voltage Operation
  - $-2.7 (V_{CC} = 2.7V \text{ to } 5.5V)$
  - $-2.5 (V_{CC} = 2.5V \text{ to } 5.5V)$
- 3-wire Serial Interface
- Schmitt Trigger, Filtered Inputs for Noise Suppression
- 2 MHz Clock Rate (5V)
- Self-timed Write Cycle (10 ms max)
- High Reliability
  - Endurance: 1 Million Write Cycles
  - Data Retention: 100 Years
- Automotive Grade and Extended Temperature Devices Available
- 8-lead PDIP and 8-lead JEDEC SOIC Packages

## **Description**

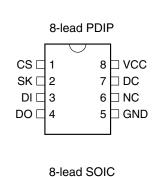
The AT93C46C provides 1024 bits of serial electrically-erasable programmable read only memory (EEPROM) organized as 64 words of 16 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The AT93C46C is available in space-saving 8-lead PDIP and 8-lead JEDEC SOIC packages.

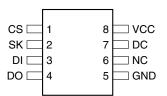
The AT93C46C is enabled through the Chip Select pin (CS) and accessed via a 3-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a READ instruction at DI, the address is decoded and the data is clocked out serially on the DO pin. The WRITE cycle is completely self-timed and no separate ERASE cycle is required before WRITE. The WRITE cycle is only enabled when the part is in the ERASE/WRITE ENABLE state. When CS is brought "high" following the initiation of a WRITE cycle, the DO pin outputs the READY/BUSY status of the part.

The AT93C46C is available in 2.7V to 5.5V and 2.5V to 5.5V versions.

Table 1. Pin Configurations

Pin Name	Function
CS	Chip Select
SK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
VCC	Power Supply
NC	No Connect
DC	Don't Connect







# 3-Wire Serial EEPROM

1K (64 x 16)

## AT93C46C





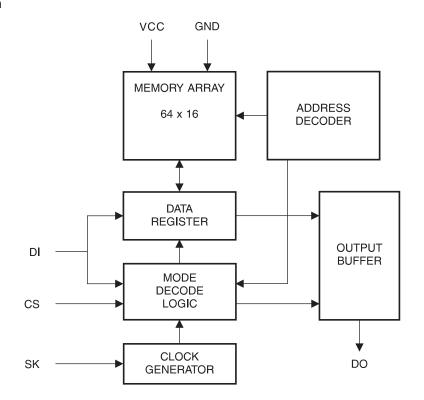
# **Absolute Maximum Ratings\***

Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on Any Pin with Respect to Ground1.0V to +7.0V
Maximum Operating Voltage
DC Output Current5.0 mA

Figure 1. Block Diagram

\*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



**Table 2.** Pin Capacitance<sup>(1)</sup>

Applicable over recommended operating range from  $T_A = 25^{\circ}C$ , f = 1.0 MHz,  $V_{CC} = +5.0V$  (unless otherwise noted)

Symbol	Symbol Test Conditions		Units	Conditions
C <sub>OUT</sub>	Output Capacitance (DO)	5	pF	$V_{OUT} = 0V$
C <sub>IN</sub>	Input Capacitance (CS, SK, DI)	5	pF	$V_{IN} = 0V$

Note: 1. This parameter is characterized and is not 100% tested.

Table 3. DC Characteristics

Applicable over recommended operating range from:  $T_{AI}$  = -40°C to +85°C,  $V_{CC}$  = +2.5V to +5.5V,  $T_{AC}$  = 0°C to +70°C,  $V_{CC}$  = +2.5V to +5.5V (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Тур	Max	Units
V <sub>CC1</sub>	Supply Voltage			2.5		5.5	V
V <sub>CC2</sub>	Supply Voltage			2.7		5.5	V
V <sub>CC3</sub>	Supply Voltage			4.5		5.5	V
	Complet Comment	V 5.0V	READ at 1.0 MHz		0.5	2.0	mA
I <sub>CC</sub>	Supply Current	$V_{CC} = 5.0V$	WRITE at 1.0 MHz		0.5	2.0	mA
I <sub>SB1</sub>	Standby Current	V <sub>CC</sub> = 2.5V	CS = 0V		14.0	20.0	μΑ
I <sub>SB2</sub>	Standby Current	V <sub>CC</sub> = 2.7V	CS = 0V		14.0	20.0	μΑ
I <sub>SB3</sub>	Standby Current	V <sub>CC</sub> = 5.0V	CS = 0V		35.0	50.0	μΑ
I <sub>IL</sub>	Input Leakage	V <sub>IN</sub> = 0V to V <sub>CC</sub>			0.1	1.0	μΑ
I <sub>OL</sub>	Output Leakage	$V_{IN} = 0V \text{ to } V_{CC}$			0.1	1.0	μΑ
V <sub>IL1</sub> <sup>(1)</sup> V <sub>IH1</sub> <sup>(1)</sup>	Input Low Voltage Input High Voltage	$2.5V \le V_{CC} \le 5.5V$		-0.6 V <sub>CC</sub> x 0.7		V <sub>CC</sub> x 0.3 V <sub>CC</sub> + 1	V
V <sub>OL1</sub>	Output Low Voltage	45)/ ()/ (55)/	I <sub>OL</sub> = 2.1 mA			0.4	V
V <sub>OH1</sub>	Output High Voltage	$4.5V \le V_{CC} \le 5.5V$	I <sub>OH</sub> = -0.4 mA	2.4			V
V <sub>OL2</sub>	Output Low Voltage	0.577 < 0.277	I <sub>OL</sub> = 0.15 mA			0.2	V
V <sub>OH2</sub>	Output High Voltage	$2.5V \le V_{CC} \le 2.7V$	$I_{OH} = -100 \mu A$	V <sub>CC</sub> - 0.2			V

Note: 1.  $V_{IL}$  min and  $V_{IH}$  max are reference only and are not tested.





Table 4. AC Characteristics

Applicable over recommended operating range from  $T_A = -40^{\circ}C$  to + 85°C,  $V_{CC} = +2.5V$  to + 5.5V, CL = 1 TTL Gate and 100 pF (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Тур	Max	Units
f <sub>SK</sub>	SK Clock Frequency	$4.5V \le V_{CC} \le 5.5$ $2.7V \le V_{CC} \le 5.5$ $2.5V \le V_{CC} \le 5.5$	5V	0 0 0		2 1 0.5	MHz
t <sub>SKH</sub>	SK High Time	$4.5V \le V_{CC} \le 5.5$ $2.7V \le V_{CC} \le 5.5$ $2.5V \le V_{CC} \le 5.5$	5V	250 250 500			ns
t <sub>SKL</sub>	SK Low Time	$4.5V \le V_{CC} \le 5.5$ $2.7V \le V_{CC} \le 5.5$ $2.5V \le V_{CC} \le 5.5$	5V	250 250 500			ns
t <sub>CS</sub>	Minimum CS Low Time	$4.5V \le V_{CC} \le 5.5$ $2.7V \le V_{CC} \le 5.5$ $2.5V \le V_{CC} \le 5.5$	5V	250 250 500			ns
t <sub>CSS</sub>	CS Setup Time	Relative to SK	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 2.5V \leq V_{CC} \leq 5.5V \end{array}$	50 50 100			ns
t <sub>DIS</sub>	DI Setup Time	Relative to SK	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 2.5V \leq V_{CC} \leq 5.5V \end{array}$	100 100 200			ns
t <sub>CSH</sub>	CS Hold Time	Relative to SK		0			ns
t <sub>DIH</sub>	DI Hold Time	Relative to SK	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 2.5V \leq V_{CC} \leq 5.5V \end{array}$	100 100 200			ns
t <sub>PD1</sub>	Output Delay to "1"	AC Test	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 2.5V \leq V_{CC} \leq 5.5V \end{array}$			250 250 500	ns
t <sub>PD0</sub>	Output Delay to "0"	AC Test	$\begin{array}{l} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 2.5V \leq V_{CC} \leq 5.5V \end{array}$			250 250 500	ns
t <sub>SV</sub>	CS to Status Valid	AC Test	$\begin{array}{l} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 2.5V \leq V_{CC} \leq 5.5V \end{array}$			250 250 500	ns
t <sub>DF</sub>	CS to DO in High Impedance	AC Test CS = V <sub>IL</sub>	$\begin{array}{c} 4.5V \leq V_{CC} \leq 5.5V \\ 2.7V \leq V_{CC} \leq 5.5V \\ 2.5V \leq V_{CC} \leq 5.5V \end{array}$			100 100 200	ns
t <sub>WP</sub>	Write Cycle Time					10	ms
			$4.5V \le V_{CC} \le 5.5V$	0.1	3		ms
Endurance <sup>(1)</sup>	5.0V, 25°C, Page Mode			1 M			Write Cycle

Note: 1. This parameter is characterized and is not 100% tested.

Table 5. Instruction Set for the AT93C46C

			Address		
Instruction	SB	Op Code	x 16	Comments	
READ	1	10	$A_5 - A_0$	Reads data stored in memory, at specified address	
EWEN	1	00	11XXXX	Write enable must precede all programming modes	
ERASE	1	11	$A_5 - A_0$	Erase memory location A <sub>n</sub> – A <sub>0</sub>	
WRITE	1	01	$A_5 - A_0$	Writes memory location A <sub>n</sub> – A <sub>0</sub>	
ERAL	1	00	10XXXX	Erases all memory locations. Valid only at V <sub>CC</sub> = 4.5V to 5.5V	
WRAL	1	00	01XXXX	Writes all memory locations. Valid only at V <sub>CC</sub> = 4.5V to 5.5V	
EWDS	1	00	00XXXX	Disables all programming instructions	

# Functional Description

The AT93C46C is accessed via a simple and versatile 3-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. A valid instruction starts with a rising edge of CS and consists of a Start Bit (logic "1") followed by the appropriate Op Code and the desired memory address location.

**READ (READ):** The Read (READ) instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic "0") precedes the 16-bit data output string.

**ERASE/WRITE (EWEN):** To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the EWEN state, programming remains enabled until an EWDS instruction is executed or  $V_{\rm CC}$  power is removed from the part.

**ERASE (ERASE):** The Erase (ERASE) instruction programs all bits in the specified memory location to the logical "1" state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). A logic "1" at pin DO indicates that the selected memory location has been erased, and the part is ready for another instruction.

**WRITE (WRITE):** The Write (WRITE) instruction contains the 16 bits of data to be written into the specified memory location. The self-timed programming cycle  $t_{WP}$  starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). A logic "0" at DO indicates that programming is still in progress. A logic "1" indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. A Ready/Busy Status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle  $t_{WP}$ .

**ERASE ALL (ERAL):** The Erase All (ERAL) instruction programs every bit in the memory array to the logic "1" state and is primarily used for testing purposes. The DO pin outputs the READY/BUSY status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). The ERAL instruction is valid only at  $V_{CC} = 5.0V \pm 10\%$ .



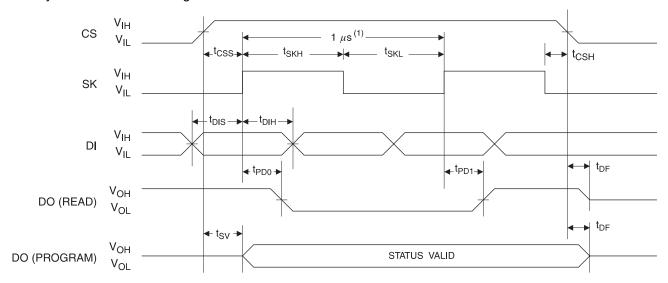


**WRITE ALL (WRAL):** The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns ( $t_{CS}$ ). The WRAL instruction is valid only at  $V_{CC} = 5.0V \pm 10\%$ .

**ERASE/WRITE DISABLE (EWDS):** To protect against accidental data disturb, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the Read instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

# **Timing Diagrams**

Figure 2. Synchronous Data Timing



Note: This is the minimum SK period.



Table 6. Organization Key for Timing Diagrams

	AT93C46C		
I/O	x 16		
A <sub>N</sub>	$A_5$		
D <sub>N</sub>	D <sub>15</sub>		

Figure 3. READ Timing

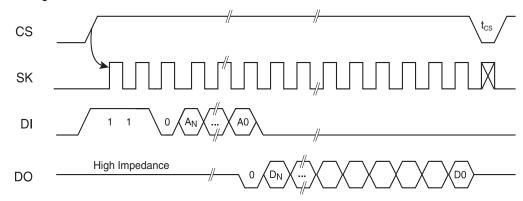
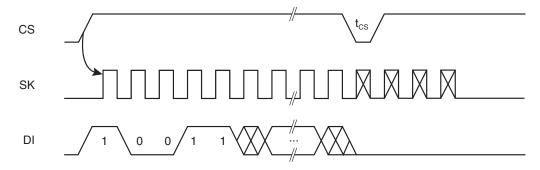
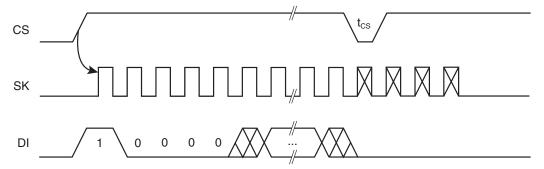


Figure 4. EWEN Timing<sup>(1)</sup>



Note: 1. Requires a minimum of nine clock cycles.

Figure 5. EWDS Timing<sup>(1)</sup>



Note: 1. Requires a minimum of nine clock cycles.

Figure 6. WRITE Timing

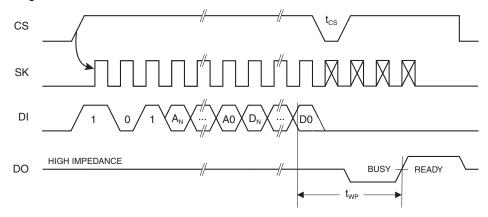
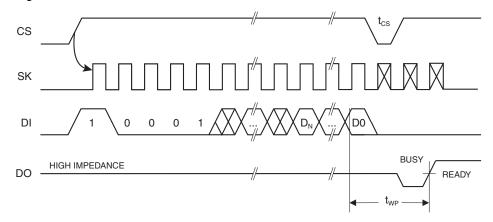


Figure 7. WRAL Timing<sup>(1)(2)</sup>



Notes: 1. Valid only at  $V_{CC} = 4.5 V$  to 5.5 V 2. Requires a minimum of nine clock cycles.

Figure 8. ERASE Timing

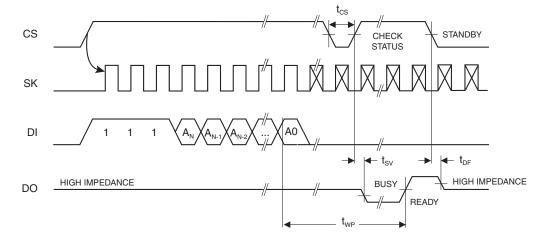
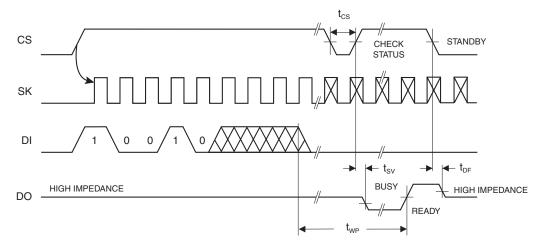






Figure 9. ERAL Timing<sup>(1)</sup>



Note: 1. Valid only at  $V_{CC} = 4.5V$  to 5.5V

# **Ordering Information**

Ordering Code	Package	Operation Range
AT93C46C-10PI-2.7	8P3	Industrial
AT93C46C-10SI-2.7	8S1	(-40°C to 85°C)
AT93C46C-10PI-2.5	8P3	Industrial
AT93C46C-10SI-2.5	8S1	(-40°C to 85°C)
		Lead-free/Halogen-free
AT93C46C-10SU-2.7	8S1	Industrial Temperature
		(-40°C to 85°C)

Note: For 2.7V and 2.5V devices used in the 4.5V to 5.5V range, please refer to performance values in the AC and DC characteristics table.

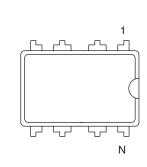
	Package Type					
8P3	8-lead, 0.300" Wide, Plastic Dual Inline Package (PDIP)					
8S1	8S1 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)					
	Options					
-2.7	<b>-2.7</b> Low Voltage (2.7V to 5.5V)					
-2.5	Low Voltage (2.5V to 5.5V)					



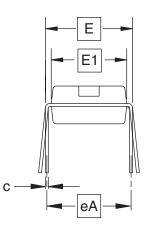


## **Packaging Information**

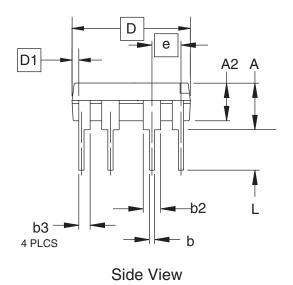
## **8P3 - PDIP**



Top View



**End View** 



#### **COMMON DIMENSIONS**

(Unit of Measure = inches)

SYMBOL	MIN	NOM	MAX	NOTE
Α			0.210	2
A2	0.115	0.130	0.195	
b	0.014	0.018	0.022	5
b2	0.045	0.060	0.070	6
b3	0.030	0.039	0.045	6
С	0.008	0.010	0.014	
D	0.355	0.365	0.400	3
D1	0.005			3
Е	0.300	0.310	0.325	4
E1	0.240	0.250	0.280	3
е	0.100 BSC			
eA	0.300 BSC			4
L	0.115	0.130	0.150	2

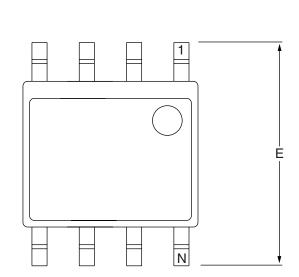
Notes

- 1. This drawing is for general information only; refer to JEDEC Drawing MS-001, Variation BA for additional information.
- 2. Dimensions A and L are measured with the package seated in JEDEC seating plane Gauge GS-3.
- 3. D, D1 and E1 dimensions do not include mold Flash or protrusions. Mold Flash or protrusions shall not exceed 0.010 inch.
- 4. E and eA measured with the leads constrained to be perpendicular to datum.
- 5. Pointed or rounded lead tips are preferred to ease insertion.
- 6. b2 and b3 maximum dimensions do not include Dambar protrusions. Dambar protrusions shall not exceed 0.010 (0.25 mm).

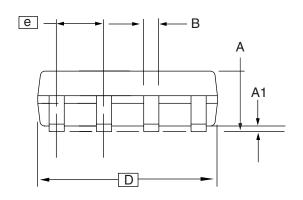
01/09/02

	_	TITLE	DRAWING NO.	REV.
AME	2325 Orchard Parkway San Jose, CA 95131	<b>8P3</b> , 8-lead, 0.300" Wide Body, Plastic Dual In-line Package (PDIP)	8P3	В

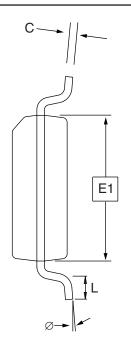
## **8S1 – JEDEC SOIC**



Top View



Side View



**End View** 

## **COMMON DIMENSIONS**

(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
Α	1.35	_	1.75	
A1	0.10	-	0.25	
b	0.31	_	0.51	
С	0.17	-	0.25	
D	4.80	-	5.00	
E1	3.81	-	3.99	
E	5.79	_	6.20	
е		1.27 BSC		
L	0.40	_	1.27	
Ø	0°	-	8°	

Note: These drawings are for general information only. Refer to JEDEC Drawing MS-012, Variation AA for proper dimensions, tolerances, datums, etc.

10/7/03



1150 E. Cheyenne Mtn. Blvd. Colorado Springs, CO 80906 **TITLE 8S1**, 8-lead (0.150" Wide Body), Plastic Gull Wing Small Outline (JEDEC SOIC)

BS1 REV.





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